

TENTATIVE TOSHIBA Photocoupler GaAlAs Ired & Photo-Diode Array

TLP191B

Telecommunication
 Programmable Controllers
 Mos Gate Driver
 MOS FET Gate Driver

The TOSHIBA mini flat coupler TLP191B is a small outline coupler, suitable for surface mount assembly. The TLP191B consists of a GaAlAs light emitting diode, optically coupled to a series connected photo diode array with shunt resistor which is suitable for MOS FET gate drive.

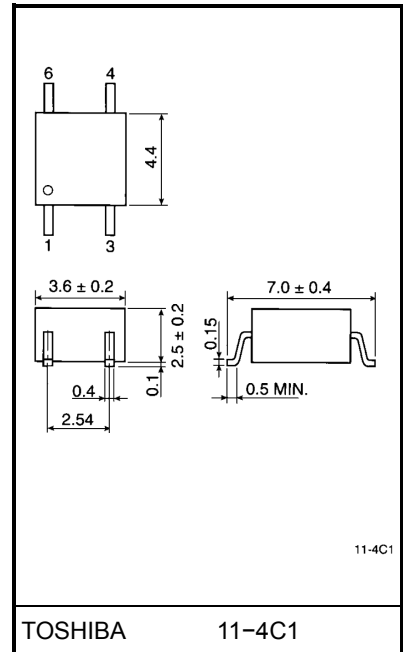
- Open voltage: 7.0V(min.)
- Short current: 24.0 μ A (min.)
- Isolation voltage: 2500 Vrms (min.)
- UL recognized: UL1577,file no.E67349

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta \geq 25°C)	$\Delta I_F / ^\circ\text{C}$	-0.5	mA / °C
	Pulse forward current (100 μ s pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	3	V
	Junction temperature	T_j	125	°C
Detector	Forward current	I_{FD}	50	μ A
	Reverse voltage	V_{RD}	10	V
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	-55~125	°C
Operating temperature range		T_{opr}	-40~80	°C
Lead soldering temperature (10s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min., R.H. \leq 60%) (Note)		BV_S	2500	Vrms

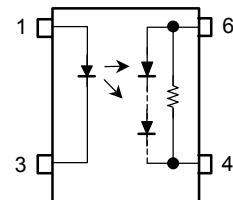
(Note) Device considered a two terminal device: Pins 1 and 3 shorted together and pins 4 and 6 shorted together.

Unit in mm



Weight: 0.09 g

Pin Configuration(top view)



- 1 . Anode
- 3 . Cathode
- 4 . Cathode
- 6 . Anode

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Forward current	I_F	—	20	25	mA
Operating temperature	T_{opr}	-25	—	85	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.2	1.4	1.7	V
	Reverse current	I_R	$V_R = 3 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	60	pF
Detector	Forward voltage	V_{FD}	$I_{FD} = 10 \mu\text{A}$	—	7	—	V
	Reverse current	I_{RD}	$V_{RD} = 10 \text{ V}$	—	7	—	μA
	Capacitance (anode to cathode)	C_{TD}	$V = 0, f = 1 \text{ MHz}$	—	—	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Open voltage	V_{OC}	$I_F = 20 \text{ mA}$	7	8	—	V
Short current	I_{SC}	$I_F = 20 \text{ mA}$	24	40	—	μA

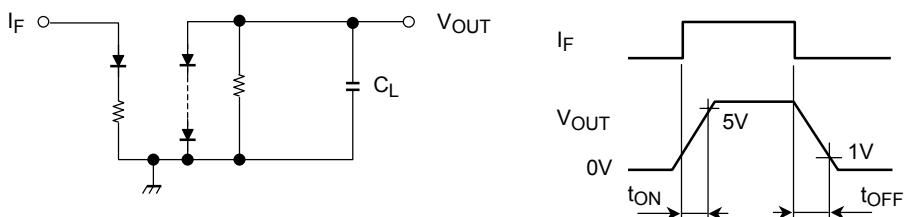
Isolation Characteristics (Ta = 25°C)

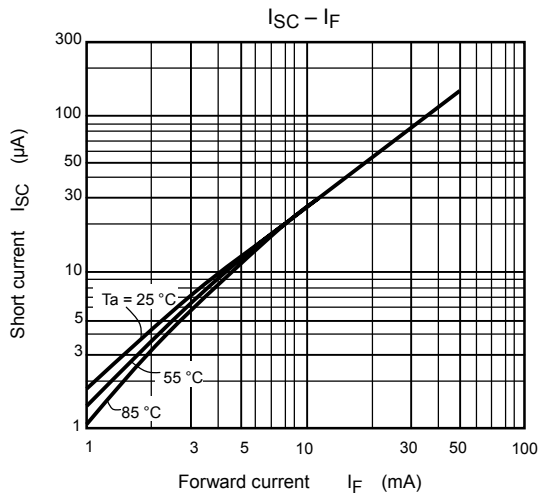
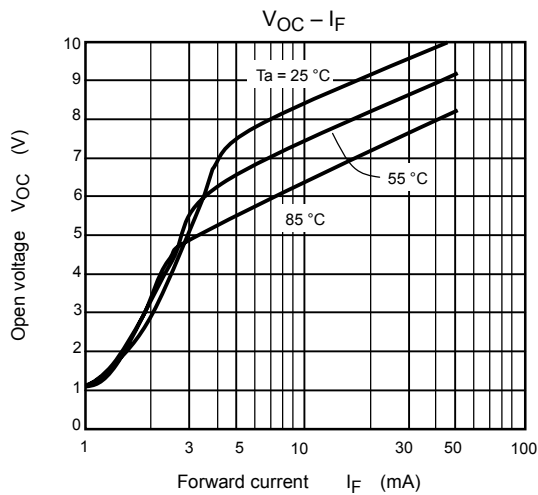
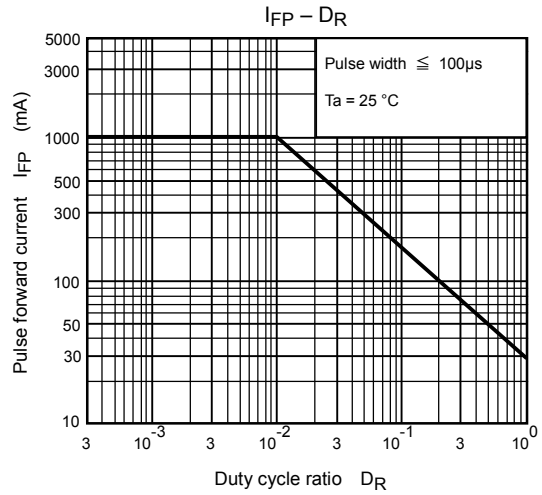
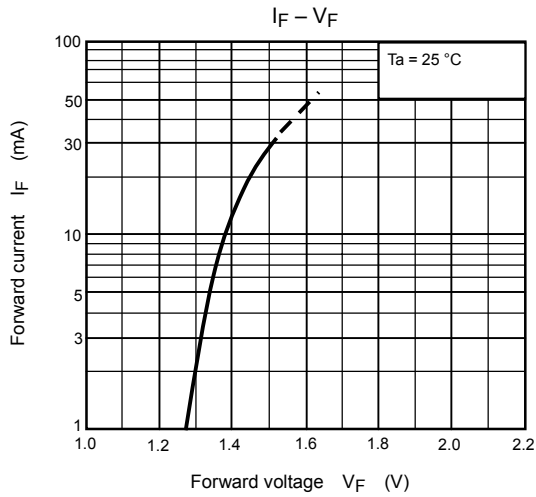
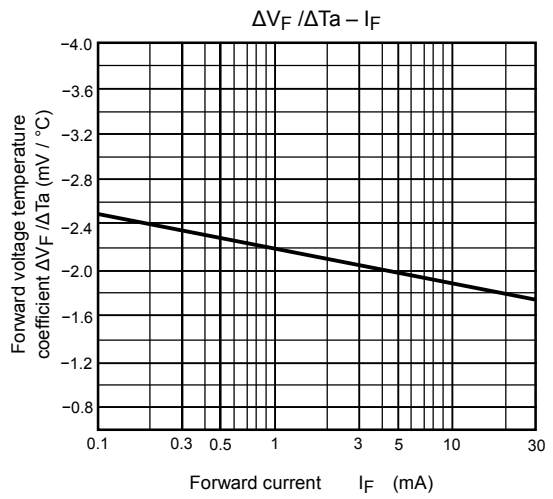
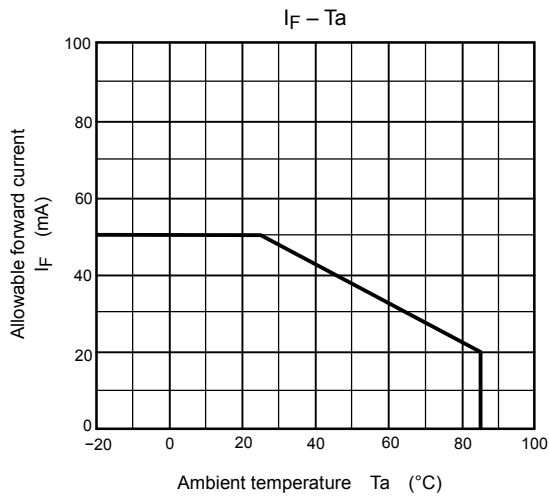
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	2500	—	—	Vrms
		AC, 1 second in oil	—	5000	—	
		DC, 1 minute in oil	—	5000	—	Vdc

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Turn-on time	t_{ON}	$I_F = 20 \text{ mA}, C_L = 1000 \text{ pF}$ (Fig.1)	—	0.2	—	ms
Turn-off time	t_{OFF}		—	3	—	ms

Fig. 1 Switching time test circuit





RESTRICTIONS ON PRODUCT USE

000707EBC

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.